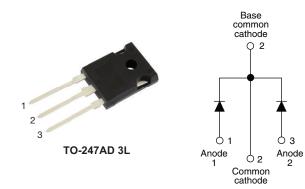
# VS-C4PU3006LHN3

**Vishay Semiconductors** 



### Ultrafast Soft Recovery Diode, 2 x 15 A FRED Pt<sup>®</sup> Gen 4



PRODUCT SUMMARY						
Package	TO-247AD 3L					
I <sub>F(AV)</sub>	2 x 15 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.12 V					
t <sub>rr</sub> typ.	See Recovery table					
T <sub>J</sub> max.	175 °C					
Diode variation	Single die					

#### FEATURES

- Gen 4 FRED Pt<sup>®</sup> technology
- $\bullet$  Low  $I_{\text{RRM}}$  and reverse recovery charge
- Very low forward voltage drop
- Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- AEC-Q101 qualified, meets JESD 201 class 2 FREE whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V<sub>F</sub>, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V				
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 146 °C	15	^				
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C$ = 25 °C, $t_p$ = 8.3 ms, half sine wave	200	A				
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-			
		I <sub>F</sub> = 15 A	-	1.32	1.55			
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.53	-	V		
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C	-	1.17	-			
Forward voltage		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.42	-			
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.12	1.28			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.38	-			
	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	15			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	16	-	pF		



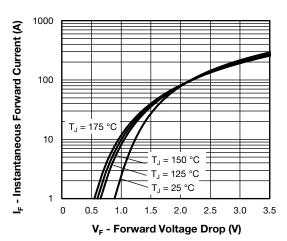
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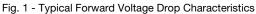


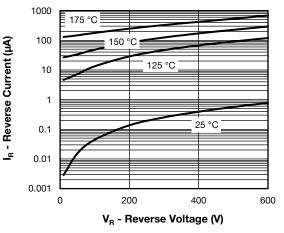
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS		
Powerse receiver time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	60	-	ns		
Reverse recovery time		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	83	-			
Peak recovery current		T <sub>J</sub> = 25 °C		-	13	-	A		
Feat recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	21	-			
Poverse receivery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	500	-	nC		
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	1100	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1.4	°C/W			
Thermal resistance, case to heat sink	R <sub>thCS</sub>		-	0.4	-				
Weight			-	6.0	-	g			
Weight			-	0.21	-	oz.			
Mounting torque			6.0	_	12	kgf · cm			
			(5)	-	(10)	$(lbf \cdot in)$			
Marking device		Case style TO-247AD 3L	C4PU3006LH						









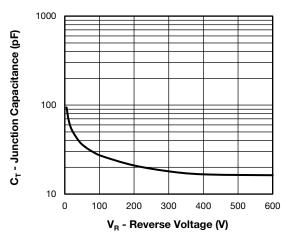


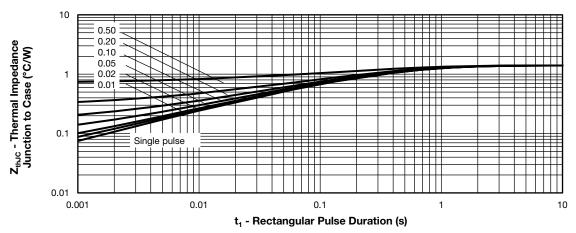
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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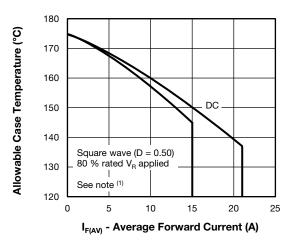
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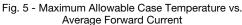
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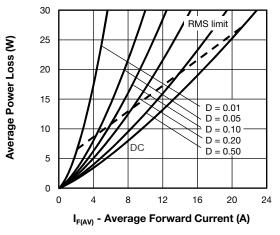






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#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC};$ 

 $\begin{array}{l} Pd = Forward \ power \ loss = I_{F(AV)} \times V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ Fig.5) \\ P_{dREV} = Inverse \ power \ loss = V_{R1} \times I_R \ (1 - D); \ I_R \ at \ V_R = rated \ V_R \end{array}$ 

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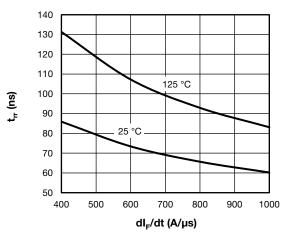
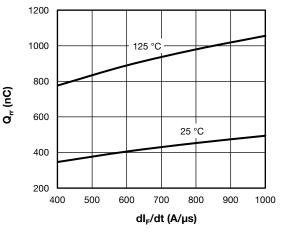


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt





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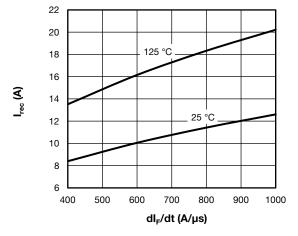


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt

### **ORDERING INFORMATION TABLE**

Device code	VS-	С	4	Р	U	30	06	L	н	N3
	1	2	3	4	5	6	7	8	9	10
	<ol> <li>Vishay Semiconductors product</li> <li>Circuit configuration: C = common diode</li> <li>FRED Pt Gen 4</li> <li>P = TO-247 package</li> <li>Process type:</li> </ol>									
	6 - 7 - 8 - 9 - 10 -	Cur Volt Pac H = Env	rent rati age rati kage: L AEC-Q ironmer	tt recove ng (30 = ng (06 = = long l 101 qua ttal digit: en-free,	= 2 x 15 = 600 V) ead lified		nt, and t	otally le	ad (Pb)	-free

ORDERING INFORMATION (Example)								
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION								
VS-C4PU3006LHN3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626				
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007				

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**Vishay Semiconductors** 

**TO-247AD 3L** 

#### **DIMENSIONS** in millimeters and inches



View B

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.209 A 4.65 5.31 0.183 0.087 0.102 A1 2.21 2.59 1.50 2.49 0.059 0.098 A2 b 0.99 1.40 0.039 0.055 b1 0.99 1.35 0.039 0.053 b2 1.65 2.39 0.065 0.094 b3 1.65 2.34 0.065 0.092 b4 2.59 3.43 0.102 0.135 b5 2.59 3.38 0.102 0.133 с 0.38 0.89 0.015 0.035 c1 0.38 0.84 0.015 0.033 D 19.71 20.70 0.776 0.815 3 D1 13.08 -0.515 4

(4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	0.2	0.254		)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	BSC	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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